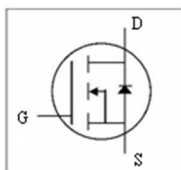
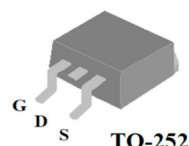


- Simple Driver Requirement
- Low On-resistance
- RoHS Compliant & Halogen-Free



BVDSS	100V
RDS(ON)Typ	8.1mΩ
ID	75A



Description

KE6802 is from Kingeavy innovated design and silicon process technology to achieve the lowest possible on- resistance and fast switching performance. It provides the designer with an extreme efficient device for use in a wide range of power applications.

Absolute Maximum Ratings@T_j=25°C(unless otherwise specified)

Symbol	Parameter	Rating	Units
VDS	Drain-Source Voltage	100	V
VGS	Gate-Source Voltage	±20	V
I _D @T _C =25°C	Drain Current, V _{GS} @ 10V	63	A
I _D @T _C =100°C	Drain Current, V _{GS} @ 10V	40	A
I _{DM}	Pulsed Drain Current ¹	110	A
P _D @T _A =25°C	Total Power Dissipation	2.1	W
P _D @T _C =25°C	Total Power Dissipation	40	W
P _D @T _C =100°C	Total Power Dissipation	16	W
E _{AS}	Avalanche Energy, Single pulse ⁴	36	mJ
T _{STG}	Storage Temperature Range	-55 to 150	°C
T _J	Operating Junction Temperature Range	150	°C

Thermal Data

Symbol	Parameter	Value	Unit
Rthj-c	Maximum Thermal Resistance, Junction-case	3	°C/W
Rthj-a	Maximum Thermal Resistance, Junction-ambient ₃	60	°C/W

Electrical Characteristics@T_j=25 °C(unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250uA	100	-	-	V
RDS(ON)	Static Drain-Source On-Resistance ₂	V _{GS} =10V, I _D =20A	-	8.1	9.7	mΩ
		V _{GS} =4.5V, I _D =20A	-	11.5	14.5	mΩ
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250uA	1	2	3	V
g _{fs}	Forward Transconductance	V _{DS} =5V, I _D =20A	-	34	-	S
I _{DSS}	Drain-Source Leakage Current	V _{DS} =80V, V _{GS} =0V	-	-	1	uA
I _{GSS}	Gate-Source Leakage	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Q _g	Total Gate Charge	I _D =20A V _{DS} =50V V _{GS} =10V	-	41	-	nC
Q _{gs}	Gate-Source Charge		-	9	-	nC
Q _{gd}	Gate-Drain ("Miller") Charge		-	10.5	-	nC
t _{d(on)}	Turn-on Delay Time	V _{DS} =50V I _D =1A R _G =6Ω V _{GS} =10V	-	9.1	-	ns
t _r	Rise Time		-	17.5	-	ns
t _{d(off)}	Turn-off Delay Time		-	32.2	-	ns
t _f	Fall Time		-	72	-	ns
C _{iss}	Input Capacitance	V _{GS} =0V V _{DS} =50V f=1.0MHz	-	2150	-	pF
C _{oss}	Output Capacitance		-	504	-	pF
Crss	Reverse Transfer Capacitance		-	35	-	pF
R _g	Gate Resistance	f=1.0MHz	-	1	-	Ω

Source-Drain Diode

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
V _{SD}	Forward On Voltage ₂	I _S =10A, V _{GS} =0V	-	0.8	1.1	V
t _{rr}	Reverse Recovery Time	I _S =10A, V _R =50V dI/dt=100A/μs	-	37.2	-	ns
Q _{rr}	Reverse Recovery Charge		-	35	-	nC

Notes:

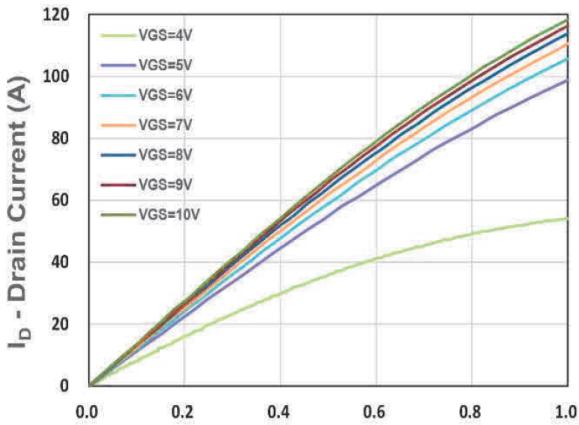
1.Pulse width limited by Max. junction temperature.

2.Pulse Test

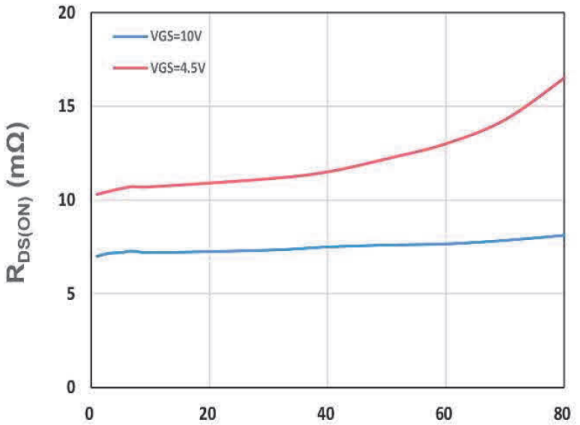
3.Surface mounted on 1 in² 2oz copper pad of FR4 board, t <10sec ; 60°C/W when mounted on min. copper pad.

4.Starting T_j=25°C V_{dd}=50V, L=0.1mH, R_g=25Ω.

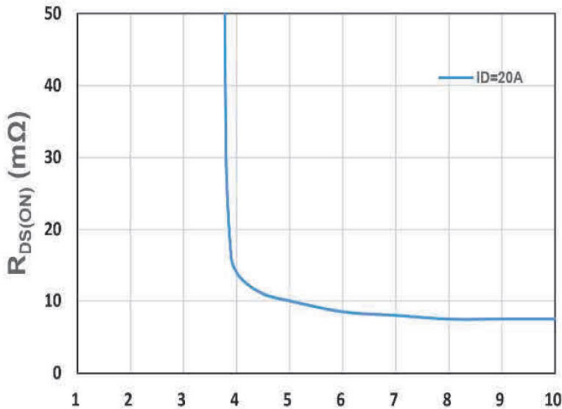
N-Channel Typical Characteristics



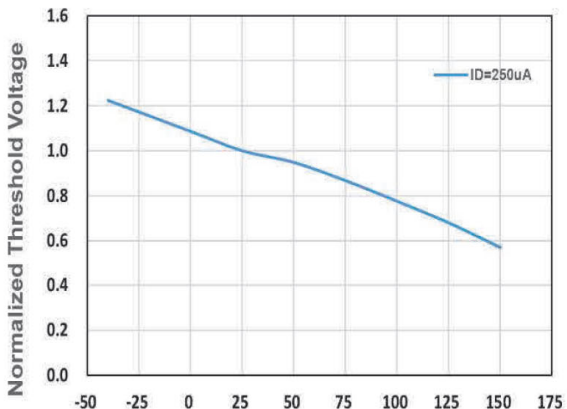
V_{DS} - Drain - Source Voltage (V)
Figure 1. Output Characteristics



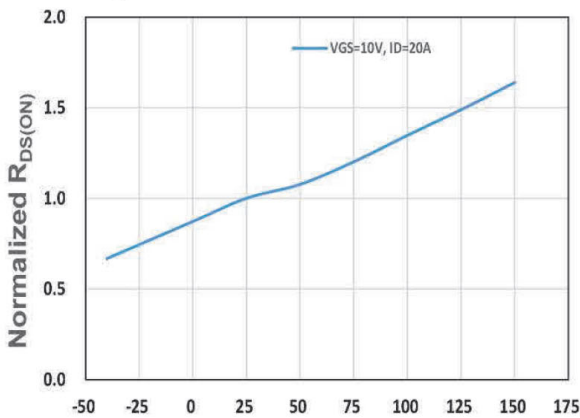
I_D - Drain Current (A)
Figure 2. On-Resistance vs. I_D



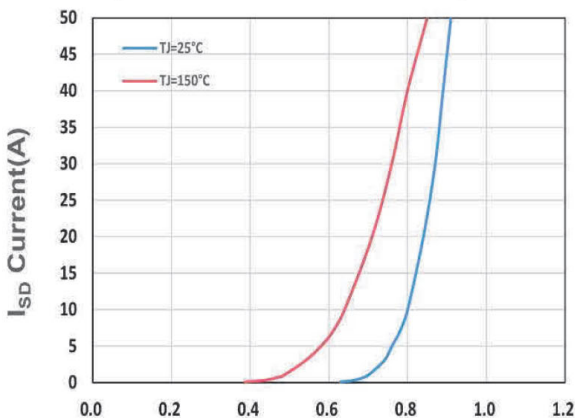
V_{GS} - Gate - Source Voltage (V)
Figure 3. On-Resistance vs. V_{GS}



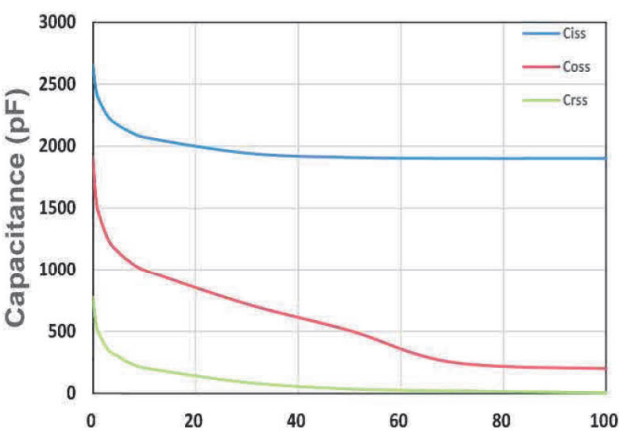
T_J , Junction Temperature($^{\circ}C$)
Figure 4. Gate Threshold Voltage



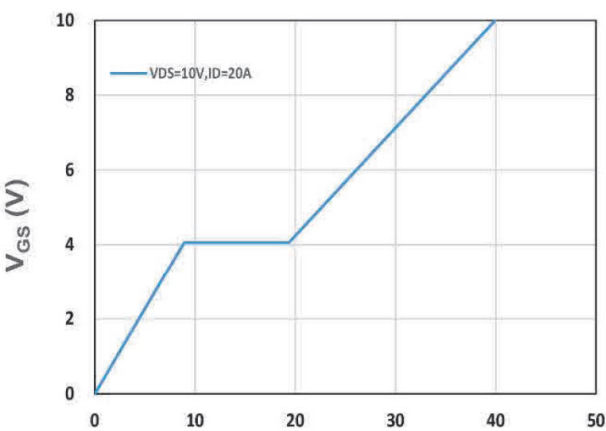
T_J , Junction Temperature($^{\circ}C$)
Figure 5. Drain-Source On Resistance



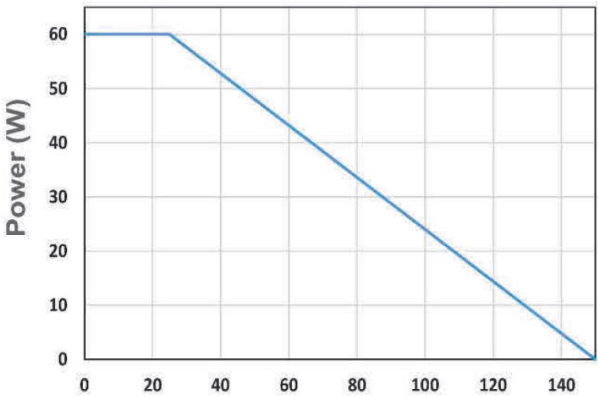
V_{SD} , Source-Drain Voltage(V)
Figure 6. Source-Drain Diode Forward



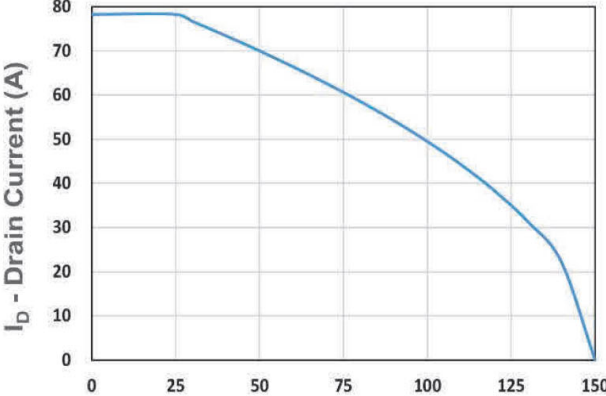
V_{DS} - Drain - Source Voltage (V)
Figure 7. Capacitance



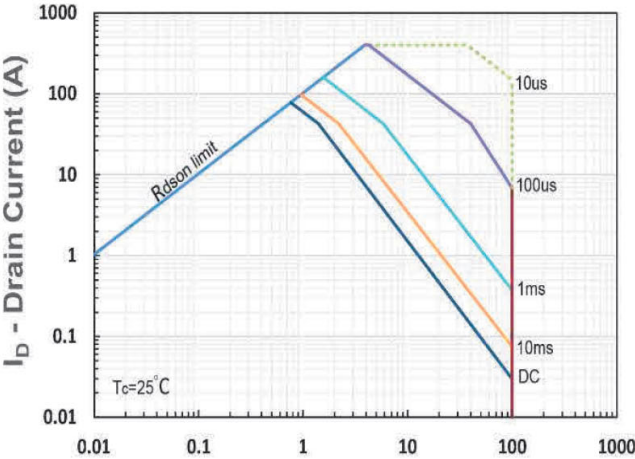
Q_g , Total Gate Charge (nC)
Figure 8. Gate Charge Characteristics



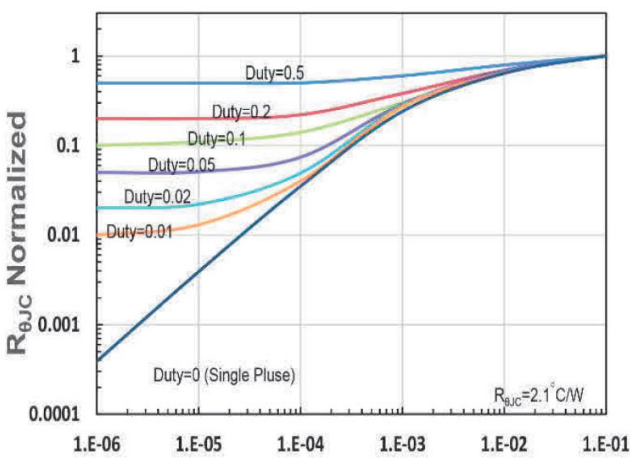
T_c - Junction Temperature ($^{\circ}C$)
Figure 9. Power Dissipation



T_c - Junction Temperature ($^{\circ}C$)
Figure 10. Drain Current

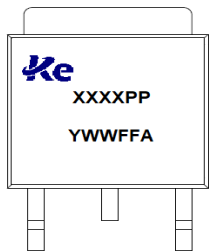


V_{DS} - Drain-Source Voltage (V)
Figure 11. Safe Operating Area



t_1 , Square Wave Pulse Duration (s)
Figure 12. $R_{\theta JC}$ Transient Thermal Impedance

Marking Information



Package	TO-252	
XXXX	Part Number	
PP	Package Code	
Y	Year	F=2020 , G=2021,
WW	Weeks	Ex. 10/27=44weeks, 11/3=45weeks
FF	Wafer lot	Lot No.
A	Serial	Serial No.
Dot	First pin	

Package Outline : TO-252 : (mm)

